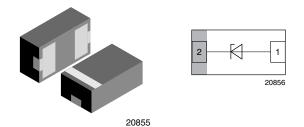
VESD12A1A-HD1

Vishay Semiconductors

ESD Protection Diode in LLP1006-2L



www.vishay.com

MARKING (example only)



Bar = cathode marking X = date code Y = type code (see table below)

DESIGN SUPPORT TOOLS click logo to get started



FEATURES

- Ultra compact LLP1006-2L package
- Low package height < 0.4 mm
- 1-line ESD protection
- Low leakage current < 0.01 μA
- Low load capacitance C_D = 22.5 pF $(V_{R} = 6 V; f = 1 MHz)$
- ESD immunity acc. IEC 61000-4-2 ± 30 kV contact discharge ± 30 kV air discharge
- High surge current acc. IEC 61000-4-5 I_{PP} > 8 A
- Soldering can be checked by standard vision inspection. No X-ray necessary
- Pin plating NiPdAu (e4) no whisker growth
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- PATENT(S): <u>www.vishay.com/patents</u>
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

| ORDERING INFORMATI | ON CONTRACTOR OF CONT | | | | |
|--------------------|---|--|------------------------|--|--|
| DEVICE NAME | ORDERING CODE | TAPED UNITS PER REEL (8 mm TAPE on 7" REEL) | MINIMUM ORDER QUANTITY | | |
| VESD12A1A-HD1 | VESD12A1A-HD1-GS08 | 8000 | 8000 | | |

| PACKAGE DATA | | | | | | | |
|---------------|-----------------|--------------|---------|---|--------------------------------------|--------------------------|--|
| DEVICE NAME | PACKAGE NAME | TYPE CODE | WEIGHT | MOLDING COMPOUND FLAMMABILITY RATING | MOISTURE SENSITIVITY LEVEL | SOLDERING CONDITIONS | |
| VESD12A1A-HD1 | LLP1006-2L | К | 0.72 mg | UL 94 V-0 | MSL level 1 (according J-STD-020) | 260 °C/10 s at terminals | |

| ABSOLUTE MAXIMUM RATINGS VESD12A1A-HD1 | | | | | | |
|--|--|------------------|-------------|------|--|--|
| PARAMETER | TEST CONDITIONS | SYMBOL | VALUE | UNIT | | |
| Peak pulse current | Acc. IEC 61000-4-5; $t_P = 8/20 \ \mu s$; single shot | I _{PPM} | 8 | А | | |
| Peak pulse power | Acc. IEC 61000-4-5; $t_P = 8/20 \ \mu s$; single shot | P _{PP} | 200 | W | | |
| ESD immunity | Contact discharge acc. IEC 61000-4-2; 10 pulses | | ± 30 | kV | | |
| | Air discharge acc. IEC 61000-4-2; 10 pulses | V _{ESD} | ± 30 | kV | | |
| Operating temperature | Junction temperature | TJ | -40 to +125 | °C | | |
| Storage temperature | | T _{stg} | -55 to +150 | °C | | |

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and international patents.





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| ELECTRICAL CHARACTERISTICS VESD12A1A-HD1 (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|--|---|----------------------|------|--------|------|-------|--|
| PARAMETER | TEST CONDITIONS/REMARKS | SYMBOL | MIN. | TYP. | MAX. | UNIT | |
| Protection paths | Number of line which can be protected | N _{channel} | - | - | 1 | lines | |
| Reverse stand-off voltage | Max. reverse working voltage | V _{RWM} | - | - | 12 | V | |
| Reverse voltage | At I _R = 0.1 μA | V _R | 12 | - | - | V | |
| Reverse current | At V _R = 12 V | I _R | - | < 0.01 | 0.1 | μA | |
| Reverse breakdown voltage | At I _R = 1 mA | V _{BR} | 13.5 | 14 | 16 | V | |
| Deverse elemening veltage | At I _{PP} = 1 A | V _C | - | 14.8 | 17 | V | |
| Reverse clamping voltage | At IPP = IPPM = 8 A | V _C | - | 21 | 24 | V | |
| | At I _{PP} = 0.2 A | V _F | - | 0.85 | 1.2 | V | |
| Forward clamping voltage | At I _{PP} = 1 A | V _F | - | 1.0 | 1.3 | V | |
| | At I _{PP} = I _{PPM} = 8 A | V _F | - | 2.0 | 2.5 | V | |
| Canacitance | At $V_R = 0 V$; f = 1 MHz | CD | - | 54 | 65 | pF | |
| Capacitance | At $V_R = 6 V$; f = 1 MHz | CD | - | 22.5 | - | pF | |

BiAs-MODE (bidirectional asymmetrical protection mode)

With the VESD12A1A-HD1 one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V_{RWM}) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage (V_C) is defined by the breakthrough voltage (V_{BR}) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V_F) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the VESD12A1A-HD1 clamping behaviour is bidirectional and asymmetrical (BiAs).

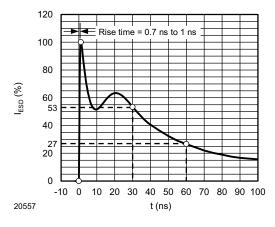


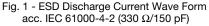
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TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)





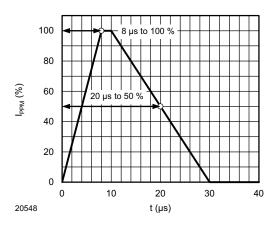


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

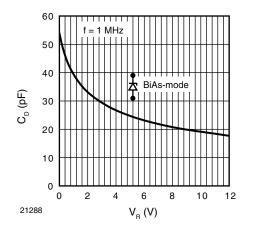


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

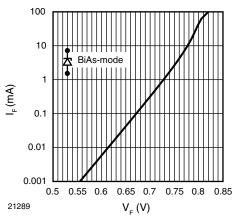
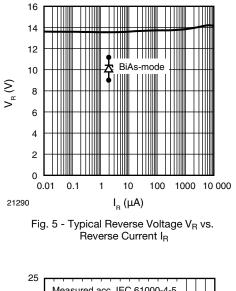
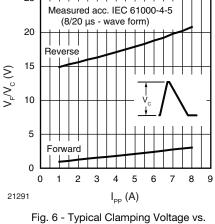


Fig. 4 - Typical Forward Current I_F vs. Forward Voltage V_F





Peak Pulse Current IPP



VESD12A1A-HD1

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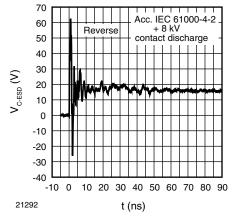


Fig. 7 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

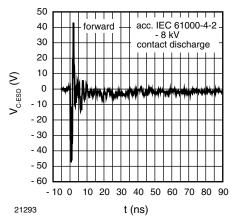
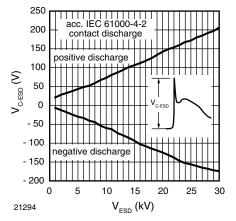
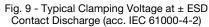


Fig. 8 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

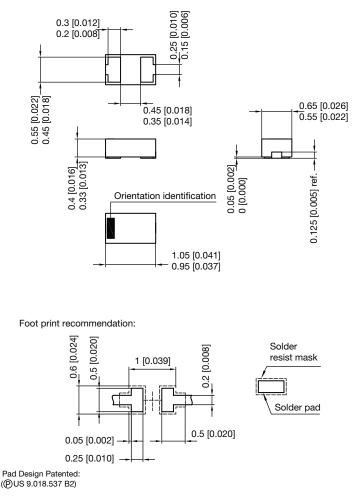




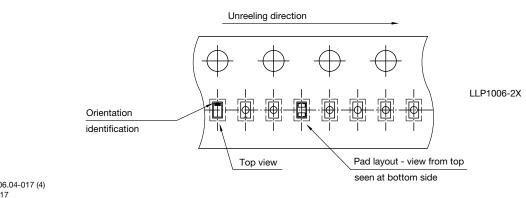


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PACKAGE DIMENSIONS in millimeters (inches): LLP1006-2L



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